

OCTAL BUFFER/LINE DRIVER; 3-STATE; INVERTING

FEATURES

- Inverting outputs
- Output capability: bus driver
- I_{CC} category: MSI

GENERAL DESCRIPTION

The 74HC/HCT540 are high-speed Si-gate CMOS devices and are pin compatible with low power Schottky TTL (LSTTL). They are specified in compliance with JEDEC standard no. 7A.

The 74HC/HCT540 are octal inverting buffer/line drivers with 3-state outputs. The 3-state outputs are controlled by the output enable inputs \bar{OE}_1 and \bar{OE}_2 . A HIGH on \bar{OE}_n causes the outputs to assume a high impedance OFF-state.

The "540" is identical to the "541" but has inverting outputs.

SYMBOL	PARAMETER	CONDITIONS	TYPICAL		UNIT
			HC	HCT	
t_{PHL}/t_{PLH}	propagation delay A_n to \bar{Y}_n	$C_L = 15 \text{ pF}$ $V_{CC} = 5 \text{ V}$	9	11	ns
C_I	input capacitance		3.5	3.5	μF
CPD	power dissipation capacitance per buffer	notes 1 and 2	39	44	μW

GND = 0 V; $T_{amb} = 25^\circ\text{C}$; $t_f = t_r = 6 \text{ ns}$

Notes

1. CPD is used to determine the dynamic power dissipation (P_D in μW):

$$P_D = CPD \times V_{CC}^2 \times f_i + \Sigma (C_L \times V_{CC}^2 \times f_o) \text{ where:}$$

f_i = input frequency in MHz C_L = output load capacitance in pF
 f_o = output frequency in MHz V_{CC} = supply voltage in V
 $\Sigma (C_L \times V_{CC}^2 \times f_o)$ = sum of outputs

2. For HC the condition is $V_I = \text{GND}$ to V_{CC}
For HCT the condition is $V_I = \text{GND}$ to $V_{CC} - 1.5 \text{ V}$

PACKAGE OUTLINES

SEE PACKAGE INFORMATION SECTION

PIN DESCRIPTION

PIN NO.	SYMBOL	NAME AND FUNCTION
1, 19	\bar{OE}_1, \bar{OE}_2	output enable input (active LOW)
2, 3, 4, 5, 6, 7, 8, 9	A_0 to A_7	data inputs
10	GND	ground (0 V)
18, 17, 16, 15, 14, 13, 12, 11	\bar{Y}_0 to \bar{Y}_7	bus outputs
20	V_{CC}	positive supply voltage

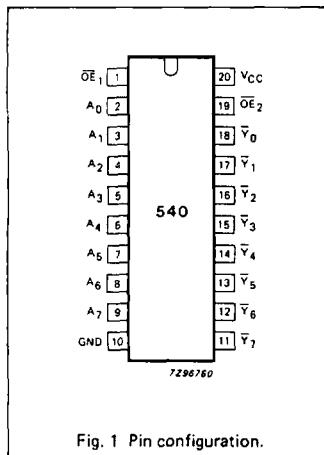


Fig. 1 Pin configuration.

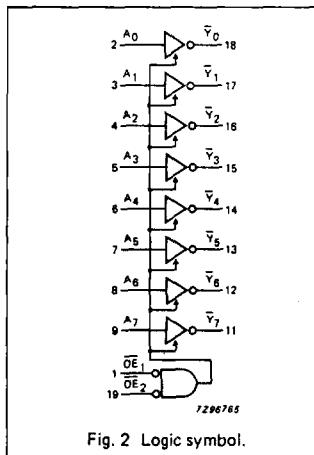


Fig. 2 Logic symbol.

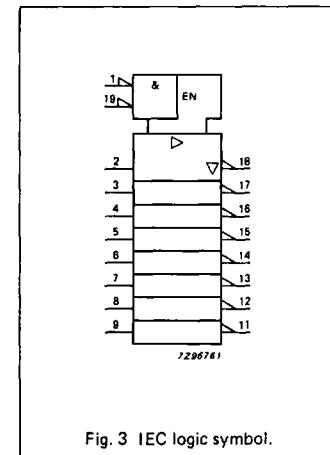


Fig. 3 IEC logic symbol.

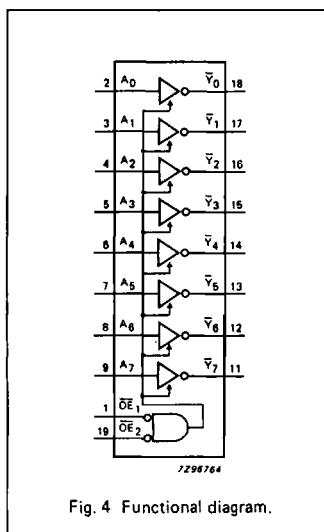


Fig. 4 Functional diagram.

FUNCTION TABLE

INPUTS			OUTPUT
\bar{OE}_1	\bar{OE}_2	A_n	\bar{Y}_n
L	L	L	H
L	X	H	L
X	X	X	Z
H	X	X	Z

H = HIGH voltage level

L = LOW voltage level

X = don't care

Z = high impedance OFF-state

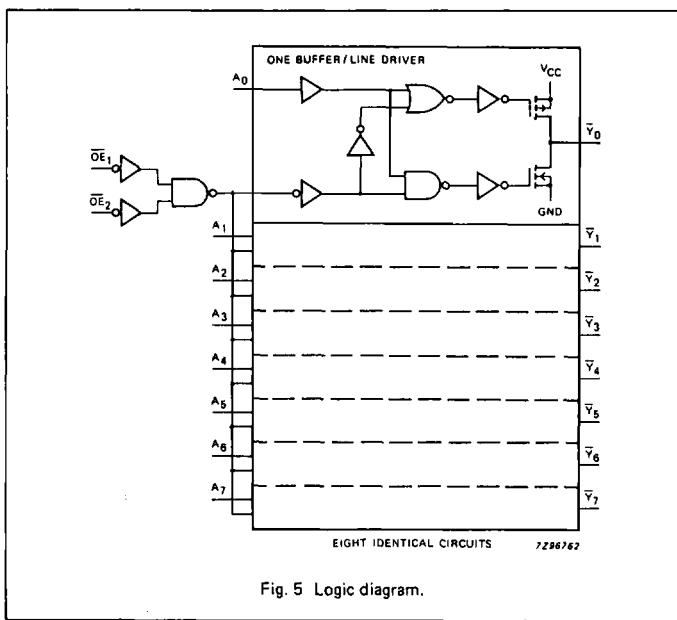


Fig. 5 Logic diagram.

DC CHARACTERISTICS FOR 74HC

For the DC characteristics see chapter "HCMOS family characteristics", section "Family specifications".

Output capability: bus driver

I_{CC} category: MSI**AC CHARACTERISTICS FOR 74HC**GND = 0 V; t_r = t_f = 6 ns; C_L = 50 pF

SYMBOL	PARAMETER	T _{amb} (°C)						UNIT	TEST CONDITIONS			
		74HC							V _{CC} V	WAVEFORMS		
		+25			−40 to +85		−40 to +125					
		min.	typ.	max.	min.	max.	min.	max.				
t _{PHL} / t _{PLH}	propagation delay A _n to Y _n	30 11 9	100 20 17		125 25 21		150 30 26	ns	2.0 4.5 6.0	Fig. 6		
t _{PZH} / t _{PZL}	3-state output enable time OE _n to Y _n	52 19 15	160 32 27		200 40 34		240 48 41	ns	2.0 4.5 6.0	Fig. 7		
t _{PHZ} / t _{PLZ}	3-state output disable time OE _n to Y _n	61 22 18	160 32 27		200 40 34		240 48 41	ns	2.0 4.5 6.0	Fig. 7		
t _{THL} / t _{TLH}	output transition time	14 5 4	60 12 10		75 15 13		90 18 15	ns	2.0 4.5 6.0	Fig. 6		

DC CHARACTERISTICS FOR 74HCT

For the DC characteristics see chapter "HCMOS family characteristics", section "Family specifications".

Output capability: bus driver
I_{CC} category: MSI

Note to HCT types

The value of additional quiescent supply current (ΔI_{CC}) for a unit load of 1 is given in the family specifications.
To determine ΔI_{CC} per input, multiply this value by the unit load coefficient shown in the table below.

INPUT	UNIT LOAD COEFFICIENT
$\bar{O}E_1$	1.50
$\bar{O}E_2$	1.00
A_n	1.40

AC CHARACTERISTICS FOR 74HCT

GND = 0 V; $t_f = t_r = 6$ ns; $C_L = 50$ pF

SYMBOL	PARAMETER	T_{amb} (°C)						UNIT	TEST CONDITIONS			
		74HCT							V _{CC} V	WAVEFORMS		
		+25			−40 to +85		−40 to +125					
		min.	typ.	max.	min.	max.	min.	max.				
t_{PHL}/t_{PLH}	propagation delay A_n to \bar{Y}_n		13	24		30		36	ns	4.5	Fig. 6	
t_{PZH}/t_{PZL}	3-state output enable time $\bar{O}E_n$ to \bar{Y}_n		22	35		44		53	ns	4.5	Fig. 7	
t_{PHZ}/t_{PLZ}	3-state output disable time $\bar{O}E_n$ to \bar{Y}_n		23	35		44		53	ns	4.5	Fig. 7	
t_{THL}/t_{TLH}	output transition time		5	12		15		18	ns	4.5	Fig. 6	

AC WAVEFORMS

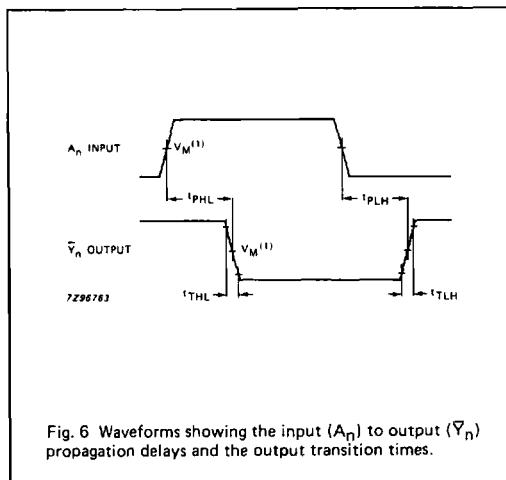
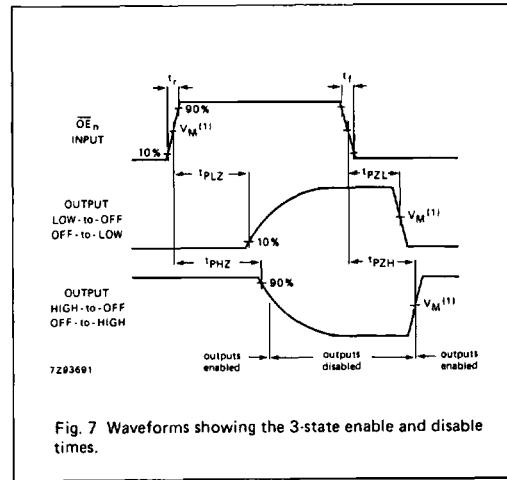
Fig. 6 Waveforms showing the input (A_n) to output (\bar{Y}_n) propagation delays and the output transition times.

Fig. 7 Waveforms showing the 3-state enable and disable times.

Note to AC waveforms

- (1) HC : $V_M = 50\%$; $V_I = \text{GND to } V_{CC}$.
- HCT: $V_M = 1.3\text{ V}$; $V_I = \text{GND to } 3\text{ V}$.